



# 10A, 35V - 200V Schottky Barrier Rectifier

#### **FEATURES**

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

#### **MECHANICAL DATA**

- Case: TO-220AC
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
  Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.88g (approximately)

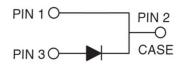
KEY PARAMETERS							
PARAMETER	VALUE	TINU					
I <sub>F</sub>	10	Α					
$V_{RRM}$	35 - 200	V					
I <sub>FSM</sub>	150	Α					
T <sub>J MAX</sub>	150	°C					
Package	TO-220AC						
Configuration	Single die						











		MBR	MBR	MBR	MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	1035	1045	1050	1060	1090	10100	10150	10200	UNIT
Marking code on the device		MBR 1035	MBR 1045	MBR 1050	MBR 1060	MBR 1090	MBR 10100	MBR 10150	MBR 10200	
Repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	90	100	150	200	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	24	31	35	42	63	70	105	140	V
Forward current	I <sub>F</sub>		10						Α	
Surge peak forward current 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	150						Α		
Peak repetitive forward current (Rated V <sub>R</sub> , Square Wave, 20KHz)	I <sub>FRM</sub>	20						А		
Peak repetitive reverse surge current <sup>(1)</sup>	I <sub>RRM</sub>	1 0.5						Α		
Voltage rate of change (Rated V <sub>R</sub> )	dV/dt	10,000						V/µs		

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	MBR 1035	MBR 1045	MBR 1050	MBR 1060	MBR 1090	MBR 10100	MBR 10150	MBR 10200	UNIT
Junction temperature	TJ		-55 to +150					°C		
Storage temperature	T <sub>STG</sub>		-55 to +175				°C			

#### Notes:

1.  $tp = 2.0\mu s$ , 1.0KHz

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-case resistance	R <sub>eJC</sub>	3	°C/W

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)								
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT		
	MBR1035 MBR1045			-	0.70	V		
	MBR1050 MBR1060	I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	0.80	V		
	MBR1090 MBR10100	IF = 10A, 1J = 23 0		-	0.85	V		
Forward voltage <sup>(1)</sup>	MBR10150 MBR10200			-	1.05	V		
Torward voltage	MBR1035 MBR1045		V F	-	0.57	V		
	MBR1050 MBR1060	I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C		-	0.70	V		
	MBR1090 MBR10100			-	0.71	V		
	MBR10150 MBR10200			-	-	V		
	MBR1035 MBR1045 MBR1050 MBR1060 MBR1090 MBR10100 MBR10150		-	100	μΑ			
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>	MBR1035 MBR1045		I <sub>R</sub>	-	15	mA		
	MBR1050 MBR1060	T <sub>J</sub> = 125°C		-	10	mA		
	MBR1090 MBR10100 MBR10150 MBR10200	1,1-120 U		-	6	mA		

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms



ORDERING INFORMATION						
ORDERING CODE <sup>(1)(2)</sup>	PACKAGE	PACKING				
MBR10x	TO-220AC	50 / Tube				
MBR10xH	TO-220AC	50 / Tube				

#### Notes:

- 1. "x" defines voltage from 35V(MBR1035) to 200V(MBR10200)
- 2. "H" means AEC-Q101 qualified



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

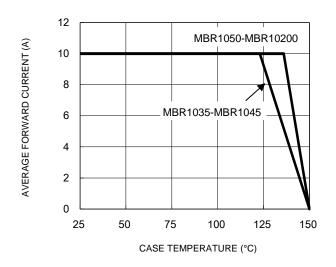


Fig.3 Typical Reverse Characteristics

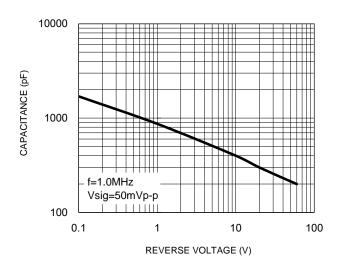
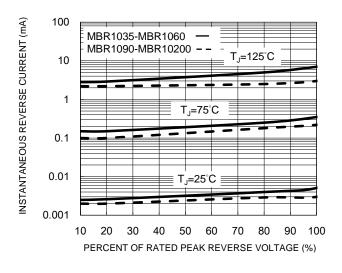


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



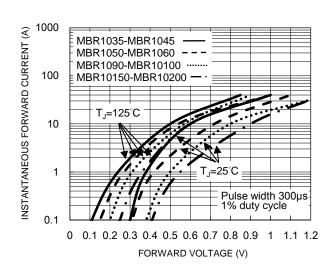
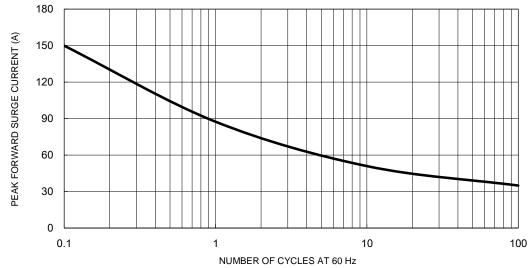


Fig.5 Maximum Non-Repetitive Forward Surge Current



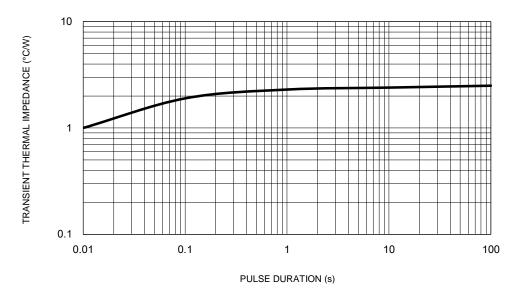
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# **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.6 Typical Transient Thermal Impedance



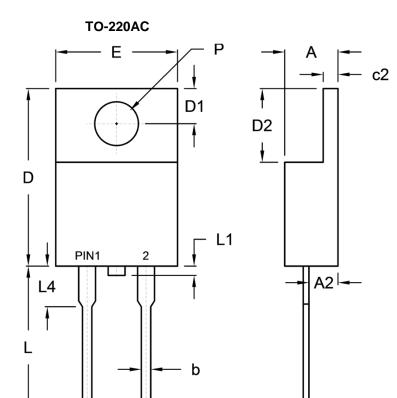
Version: M2103

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# **PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit	(mm)	Unit (	(inch)
Dilvi.	Min.	Max.	Min.	Max.
Α	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
С	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
E	-	10.50	-	0.413
e1	4.95	5.20	0.195	0.205
L	13.19	14.79	0.519	0.582
L1	0.00	1.60	0.000	0.063
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

### **MARKING DIAGRAM**



e1

P/N = Marking Code

С

6

G = Green Compound

YWW = Date Code
F = Factory Code



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